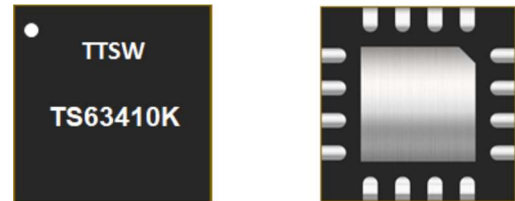


## TS63410K – GaN Broadband RF Tuning Switch 4-Bit SP4T

### 1.0 Features

- Rds-on 1.1 $\Omega$
- Coff 0.21pF
- RF peak voltage handling of 100V
- 4-BIT 16 possible independent state configurations
- No external DC blocking capacitors on RF lines
- DC Supply: Vdd=2.6~5.5V
- 1.2~5.0V GPIO bus



**Figure 1 Device Image**  
(16 Pin 3×3×0.8mm QFN Package)

### 2.0 Applications

- Tunable RF filter, Dynamic matching, and antenna tuning
- Private mobile radio handsets
- Public safety handsets
- Cellular infrastructure and Satellite terminals
- Biomedical instruments and Implant device charging

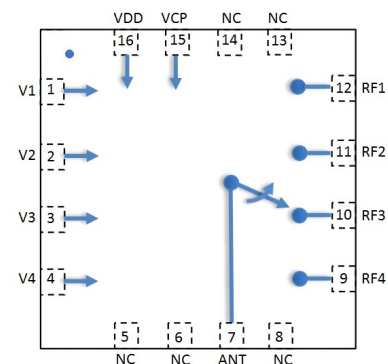


**RoHS/REACH/Halogen Free  
Compliance**

### 3.0 Description

The TS63410K is a reflective open Single Pole Four Throw (SP4T) switch designed for antenna or filter tuning applications where high RF peak voltage handling is desired. TS63410K is suitable for frequency range from 1MHz to 3GHz. The TS63410K has a very low 1.1 $\Omega$  on resistance and off capacitance of 0.21pF. This switch can select up to 16 independent states.

The TS63410K is packaged in a compact Quad Flat No lead (QFN) 3x3mm 16 leads plastic package.



**Figure 2 Function Block Diagram**  
(Top View)

### 4.0 Ordering Information

**Table 1 Ordering Information**

| Base Part Number | Package Type         | Form          | Qty  | Reel Diameter | Reel Width | Orderable Part Number |
|------------------|----------------------|---------------|------|---------------|------------|-----------------------|
| TS63410K         | 16 Pin 3×3×0.8mm QFN | Tape and Reel | 3000 | 13" (330mm)   | 18mm       | TS63410KMTRPBF        |
| Evaluation Board |                      |               |      |               |            | TS63410K-EVB          |

## 5.0 Pin Description

**Table 2 Pin Definition**

| Pin Number  | Pin Name | Description                                                |
|-------------|----------|------------------------------------------------------------|
| 1           | V1       | Switch control input 1                                     |
| 2           | V2       | Switch control input 2                                     |
| 3           | V3       | Switch control input 3                                     |
| 4           | V4       | Switch control input 4                                     |
| 5,6,8,13,14 | NC       | No internal connection, can be grounded                    |
| 7           | ANT      | Antenna port                                               |
| 9           | RF4      | RF port 4                                                  |
| 10          | RF3      | RF port 3                                                  |
| 11          | RF2      | RF port 2                                                  |
| 12          | RF1      | RF port 1                                                  |
| 15          | VCP      | Add 1nF Capacitor to Gnd on this pin                       |
| 16          | VDD      | DC power supply. Add 10nF bypass cap go Gnd close this pin |

**Note:** The backside ground (thermal) pad of the package must be grounded directly to the ground plane of PCB with multiple vias to ensure proper operation and thermal management.

## 6.0 Absolute Maximum Ratings

**Table 3 Absolute Maximum Ratings** @T<sub>A</sub>=+25°C Unless Otherwise Specified

| Parameter                                           | Symbol            | Value        | Unit |
|-----------------------------------------------------|-------------------|--------------|------|
| <b>Electrical Ratings</b>                           |                   |              |      |
| Vdd Power Supply Max Voltage                        | VDD               | 6            | V    |
| Storage Temperature Range                           | T <sub>st</sub>   | -55 to +125  | °C   |
| Operating Temperature Range                         | T <sub>op</sub>   | -40 to +85   | °C   |
| Maximum Junction Temperature                        | T <sub>J</sub>    | +140         | °C   |
| RF Input Power CW, 800MHz                           | RFx               | 41           | dBm  |
| <b>Thermal Ratings</b>                              |                   |              |      |
| Thermal Resistance (junction-to-case) – Bottom side | R <sub>θJC</sub>  | 20           | °C/W |
| Thermal Resistance (junction-to-top)                | R <sub>θJT</sub>  | ≤ 39         | °C/W |
| Soldering Temperature                               | T <sub>SOLD</sub> | 260          | °C   |
| <b>ESD Ratings</b>                                  |                   |              |      |
| Human Body Model (HBM)                              | Level 1B          | 500 to <1000 | V    |
| Charged Device Model (CDM)                          | Level C3          | ≥1000        | V    |
| <b>Moisture Rating</b>                              |                   |              |      |
| Moisture Sensitivity Level                          | MSL               | 1            | -    |

### Attention:

Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.

## 7.0 Electrical Specifications

**Table 4 Electrical Specifications** @T<sub>A</sub>=+25°C; VDD=+2.7V; 50Ω Source/Load.

| Parameter                | Condition                                                           | Minimum | Typical | Maximum | Unit |
|--------------------------|---------------------------------------------------------------------|---------|---------|---------|------|
| Operating Frequency      |                                                                     | 1       |         | 3000    | MHz  |
| ON Resistance            | On state, DC measurement                                            |         | 1.1     |         | Ω    |
| OFF Capacitance          | Total capacitance of each OFF path                                  |         | 0.21    |         | pF   |
| RF Peak Voltage          | Measured at 10MHz                                                   |         | 100     |         | V    |
| Insertion Loss, RFx      | 100MHz                                                              |         | 0.25    |         | dB   |
|                          | 500MHz                                                              |         | 0.40    |         |      |
|                          | 1.0GHz                                                              |         | 0.45    |         |      |
|                          | 2.0GHz                                                              |         | 0.85    |         |      |
|                          | 3.0GHz                                                              |         | 1.4     |         |      |
| Isolation ANT-RFx        | 100MHz                                                              |         | 40      |         | dB   |
|                          | 500MHz                                                              |         | 26      |         |      |
|                          | 1.0GHz                                                              |         | 20      |         |      |
|                          | 2.0GHz                                                              |         | 15      |         |      |
|                          | 3.0GHz                                                              |         | 12      |         |      |
| Return Loss ANT-RFx      | 100MHz                                                              |         | 43      |         | dB   |
|                          | 500MHz                                                              |         | 31      |         |      |
|                          | 1.0GHz                                                              |         | 22      |         |      |
|                          | 2.0GHz                                                              |         | 15      |         |      |
|                          | 3.0GHz                                                              |         | 11      |         |      |
| H2                       | 800MHz, Pin=35dBm                                                   |         | 80      |         | dBc  |
| H3                       | 800MHz, Pin=35dBm                                                   |         | 85      |         | dBc  |
| IIP3                     | 800MHz                                                              |         | 71      |         | dBm  |
| P0.1dB <sup>[1]</sup>    | 1~10MHz                                                             |         | 40      |         | dBm  |
|                          | 10~1000MHz                                                          |         | 42      |         | dBm  |
| Switching Time           | 50% ctrl to 10/90% of the RF value is settled. C1=1nF to Gnd on VCP |         | 2.0     |         | μs   |
| Start-up Time            | 50% ctrl to 10/90% of the RF value is settled. C1=1nF to Gnd on VCP |         | TBD     |         | μs   |
| Control Voltage          | Power supply, VDD                                                   | 2.6     | 2.7     | 5.5     | V    |
|                          | All control pins high, V <sub>ih</sub>                              | 1.0     | 2.7     | 5.25    | V    |
|                          | All control pins low, V <sub>il</sub>                               | -0.3    |         | 0.5     | V    |
| Control Current          | All control pins low, I <sub>il</sub>                               |         | 0       |         | μA   |
|                          | All control pins high, I <sub>ih</sub>                              |         |         | 7.5     | μA   |
| Current Consumption, IDD | Active mode                                                         |         | 170     | 200     | μA   |

**Note:**

[1] P0.1dB is a figure of merit.

[2] No external DC blocking capacitors required on RF pins unless DC voltage is applied on a RF pin.

[3] Start-up time is the time from VDD ON to RF signal settled on a throw or transition time from low power mode to active mode.

## 8.0 Switch Truth Table

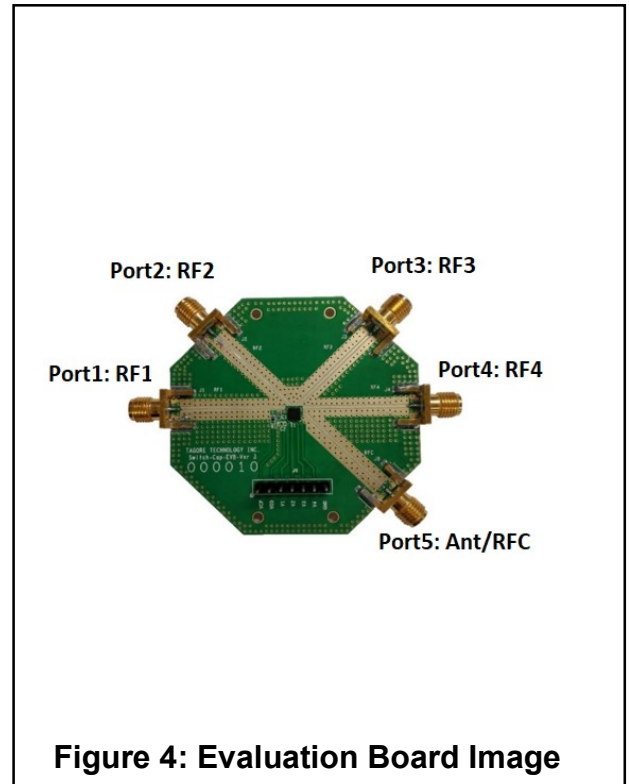
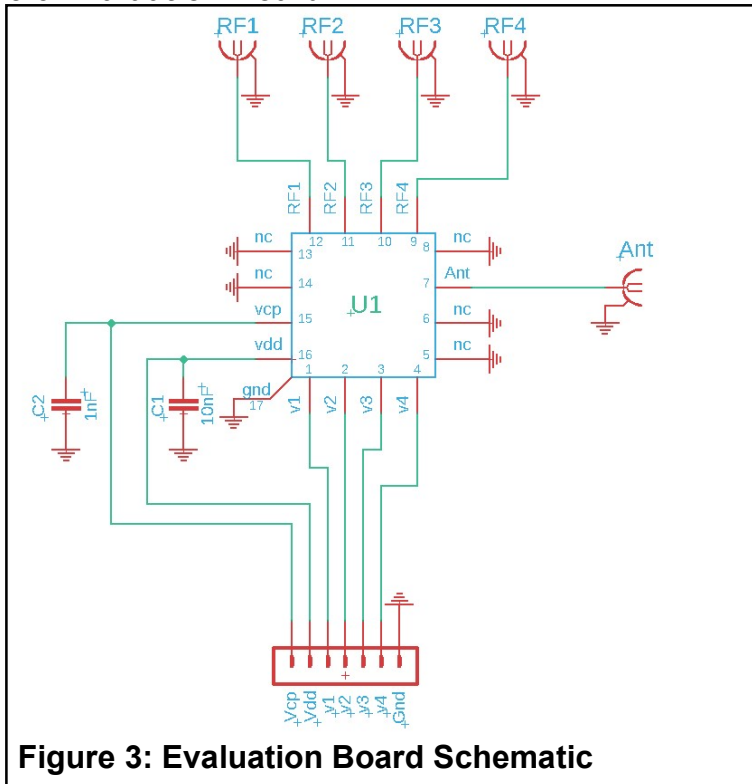
**Table 5 Switch Truth Table**

| V1 | V2 | V3 | V4 | Active RF Path |
|----|----|----|----|----------------|
| 0  | 0  | 0  | 0  | All OFF state  |
| 0  | 0  | 0  | 1  | RF4            |
| 0  | 0  | 1  | 0  | RF3            |
| 0  | 0  | 1  | 1  | RF3, RF4       |
| 0  | 1  | 0  | 0  | RF2            |
| 0  | 1  | 0  | 1  | RF2, RF4       |
| 0  | 1  | 1  | 0  | RF2, RF3       |
| 0  | 1  | 1  | 1  | RF2, RF3, RF4  |
| 1  | 0  | 0  | 0  | RF1            |
| 1  | 0  | 0  | 1  | RF1, RF4       |
| 1  | 0  | 1  | 0  | RF1, RF3       |
| 1  | 0  | 1  | 1  | RF1, RF3, RF4  |
| 1  | 1  | 0  | 0  | RF1, RF2       |
| 1  | 1  | 0  | 1  | RF1, RF2, RF4  |
| 1  | 1  | 1  | 0  | RF1, RF2, RF3  |
| 1  | 1  | 1  | 1  | All ON state   |

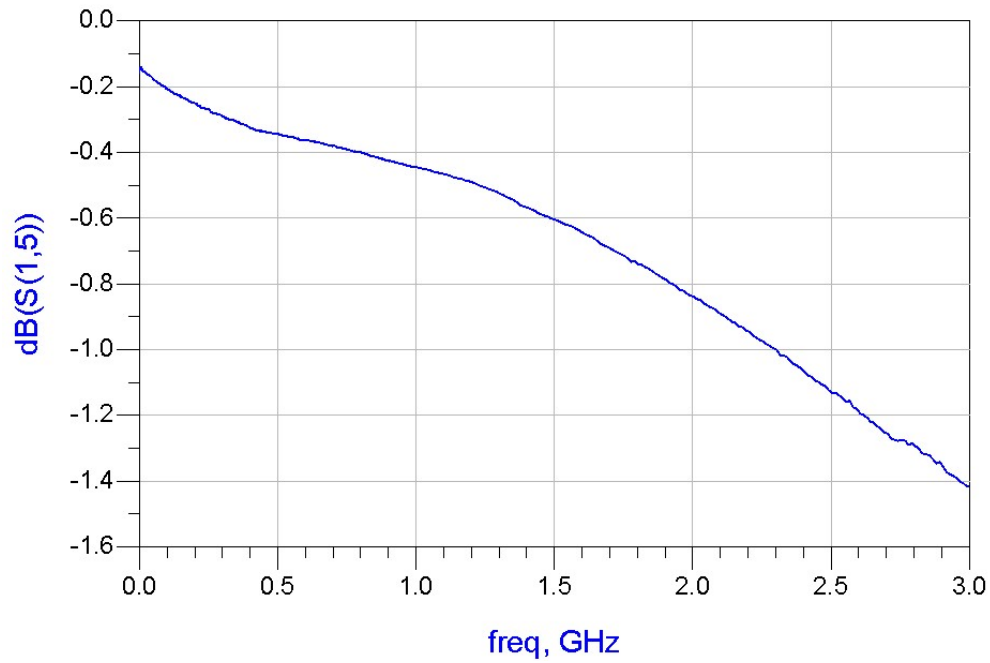
**Attention:**

- [1] VDD should be applied first before V1, V2, V3 and V4, otherwise may cause damage to the device.
- [2] There are internal pull-downs to ground on all control pins, the state at start-up without any control voltage applied will be All OFF.
- [3] If there is no DC path to ground on the ANT-to-RF port paths, the switch will not change its state. Consult Section 12.0 for more details.

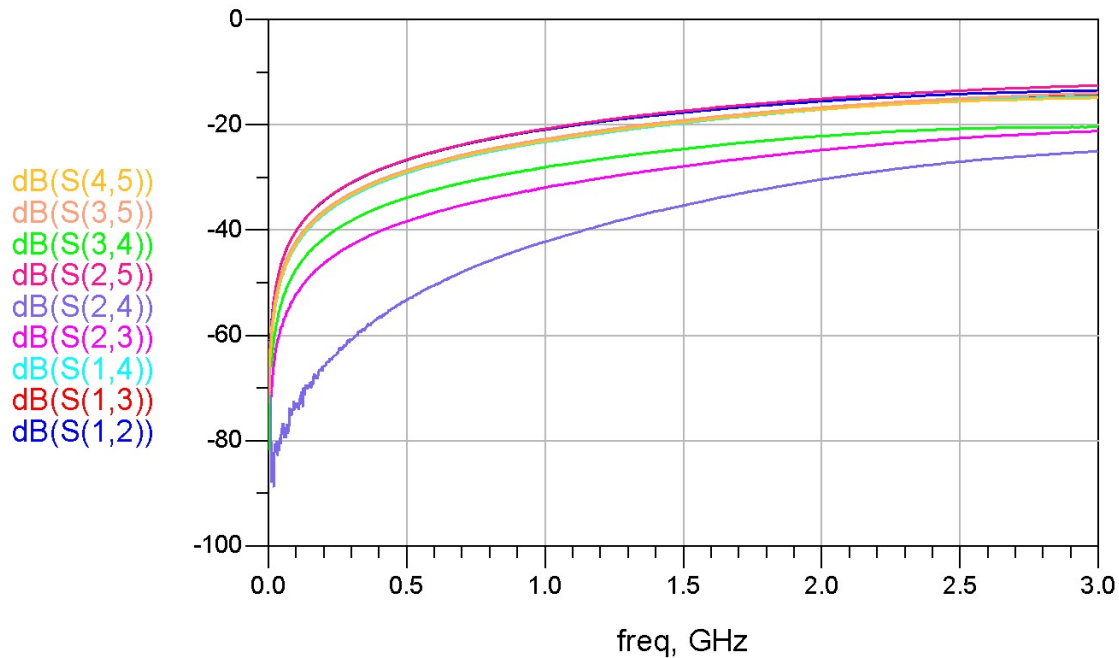
## 9.0 Evaluation Board



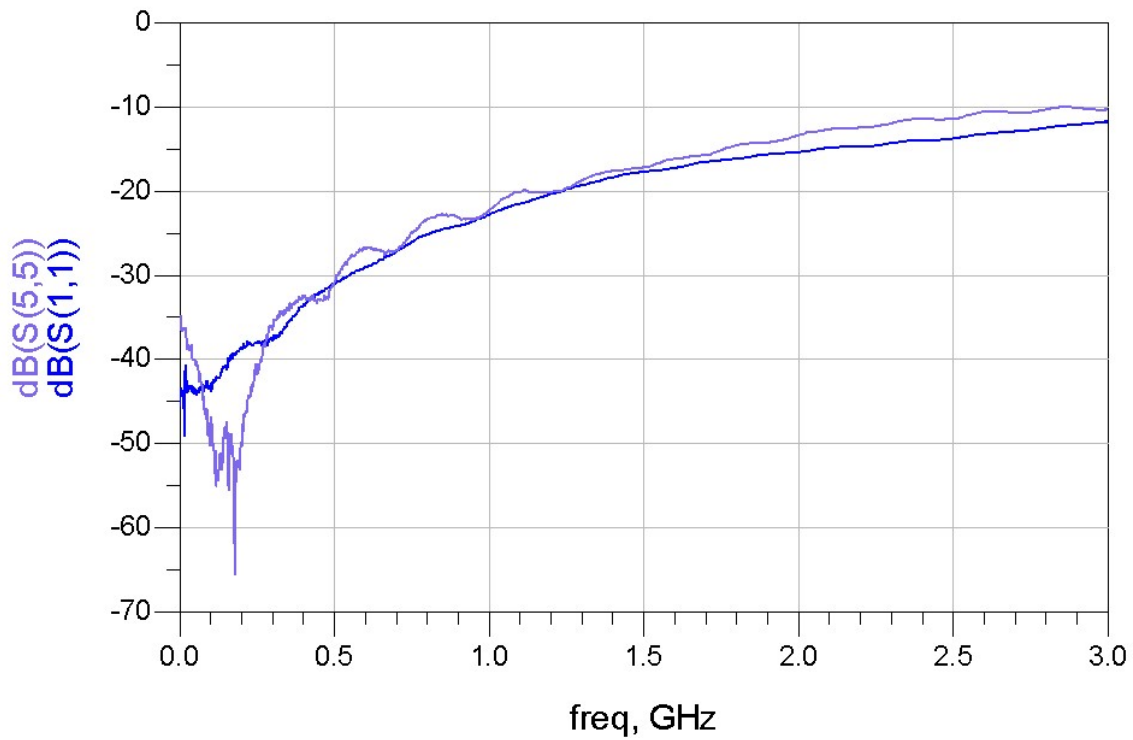
## 10.0 Typical Characteristics



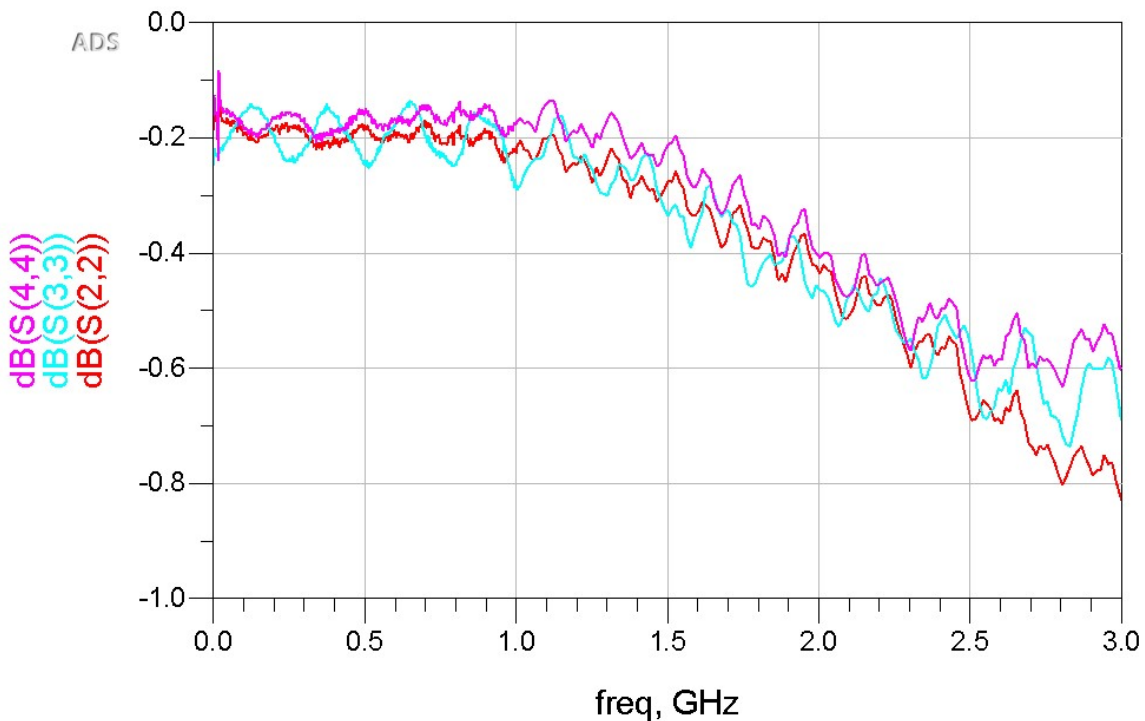
**Figure 5: Insertion Loss between RF1-Ant for RF1-On State 0001**



**Figure 6: All Port-Port Isolations for RF1-On State 0001**

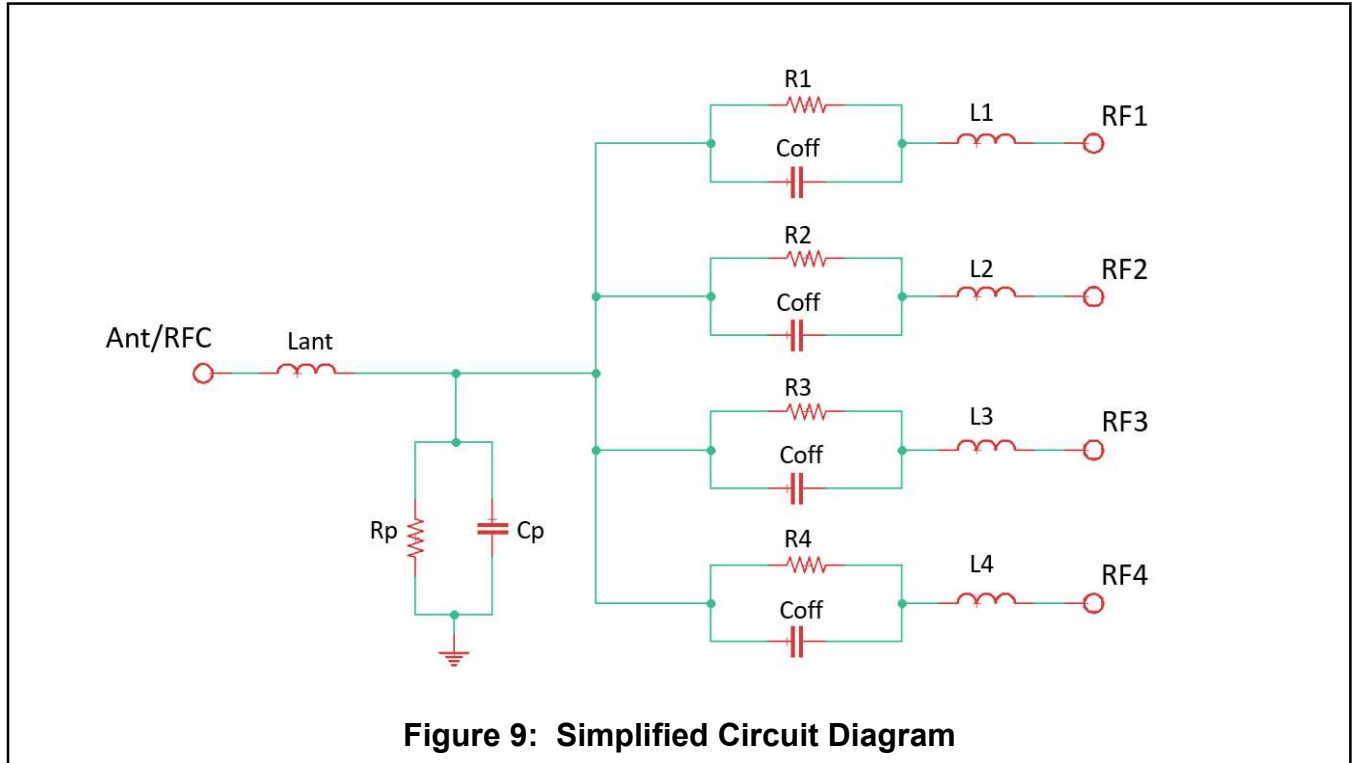


**Figure 7: On Port Return Loss for RF1 and Ant port for RF1-On State 0001**



**Figure 8: Off Port Return Loss for RF1-On State 0001**

## 11.0 Internal Circuit Diagram



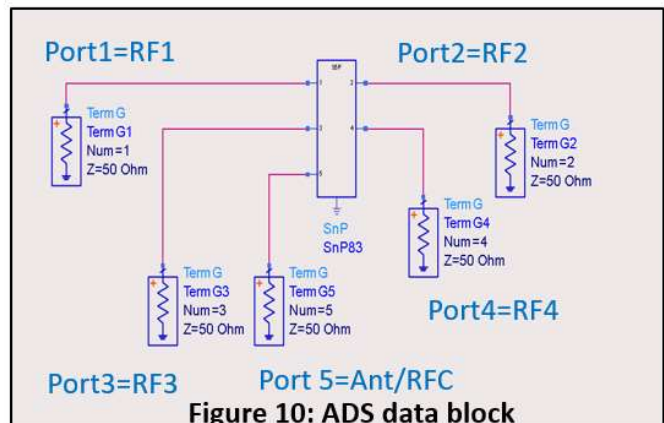
| Component | Value            | Unit     |
|-----------|------------------|----------|
| Rp        | 12.5K            | $\Omega$ |
| Cp        | 0.95             | pF       |
| Coff      | 0.21             | pF       |
| R1-R4     | 1.1 if ON State  | $\Omega$ |
|           | 78K if OFF State | $\Omega$ |
| Lant      | 0.9              | nH       |
| L1-L4     | 0.6              | nH       |

Note: Ron/Off is measured at DC. The circuit model is general purpose model, and will not accurately predict full performance, such as Q and losses in a tunable filter or antenna design. For more accuracy, it is recommended to use a customized s-parameter model which is available for download:

### SP4T tuning switch simulation model

#### Available for download

- Derived 5 Port touchstone S-parameter model file
- 16 total .S5P files for all 4-bit state combinations
- Notes:
  - Frequency up to 3GHz
  - Accurately predict Q and losses
  - Compatible with ADS/Microwave Office
  - EM simulation of PCB is recommended
  - Accurate models of external components such as inductors and capacitors is required



## Application Board 1: Tunable Band-Pass Filter 280-500MHz (1 Switch, 1 pole LC resonator)

U1=TS63420K  
L1=27nH  
(CollCraft 1111SQ Series)  
Note: inductor model SRF  
re-adjusted from vendor's  
datasheet based on  
measured data on PCB

4-Bit Ctrl Logic Bus  
V1,V2,V3,V4

**Figure 11: Schematic**



Figure 12: Evaluation Board1

Figure 13: Measured vs. Simulated Filter Response

Note: The simulation was performed using the s-parameter model on p.7 (not the circuit model)

## Application Board 2: Tunable Low-Pass Filter 500-1000MHz (2 Switch, 3 element Pi-Network)

9.1nH (CoilCraft HP603)

U1=U2=TS63420K

4-Bit Ctrl Logic Bus  
V1,V2,V3,V4

**Figure 14: Schematic**

Figure 16 displays a 4x4 grid of 16 plots comparing Measured vs. Simulated Filter Response. Each plot shows the magnitude response (Gain in dB) versus frequency (GHz) for a specific filter configuration. The plots are arranged in a 4x4 grid, with the center frequency (f0) and bandwidth (B) varying across the rows and columns.

The plots are labeled as follows:

- Row 1: f0 = 0.000, B = 0.001; f0 = 0.001, B = 0.001; f0 = 0.010, B = 0.010; f0 = 0.011, B = 0.011
- Row 2: f0 = 0.910, B = 0.910; f0 = 0.910, B = 0.910; f0 = 0.910, B = 0.910; f0 = 0.911, B = 0.911
- Row 3: f0 = 1.000, B = 1.000; f0 = 1.001, B = 1.001; f0 = 1.010, B = 1.010; f0 = 1.011, B = 1.011
- Row 4: f0 = 1.100, B = 1.100; f0 = 1.101, B = 1.101; f0 = 1.110, B = 1.110; f0 = 1.111, B = 1.111

The x-axis for all plots is frequency in GHz, ranging from 0.2 to 2.0. The y-axis is Gain in dB, ranging from -70 to 0. The plots show a sharp dip in gain at the center frequency (f0), indicating a bandpass filter response. The measured and simulated responses are closely matched across all plots.

Note: The simulation was performed using the s-parameter model on p.7 (not the circuit model)

## 12.0 Standard Tuning Switch Configurations

### 12.1 Series Configuration

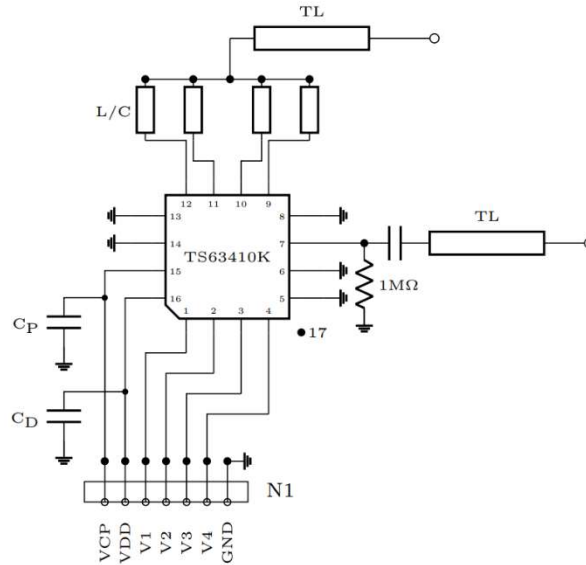


Figure 17. Series configuration. DC reference required.

Note: Series configurations require DC path since all RF and ANT ports are AC coupled. The DC reference can be provided through a 1 MΩ resistor, as shown in Fig. 17.

### 12.2 Shunt Configuration

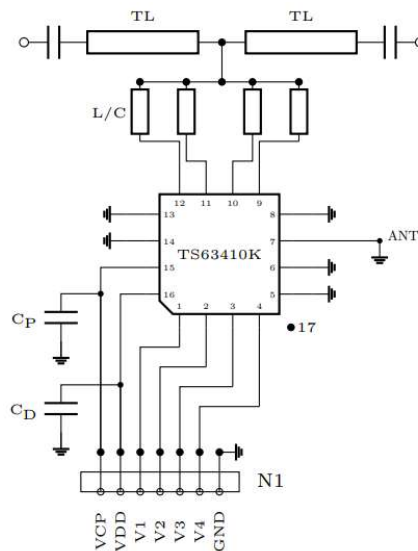
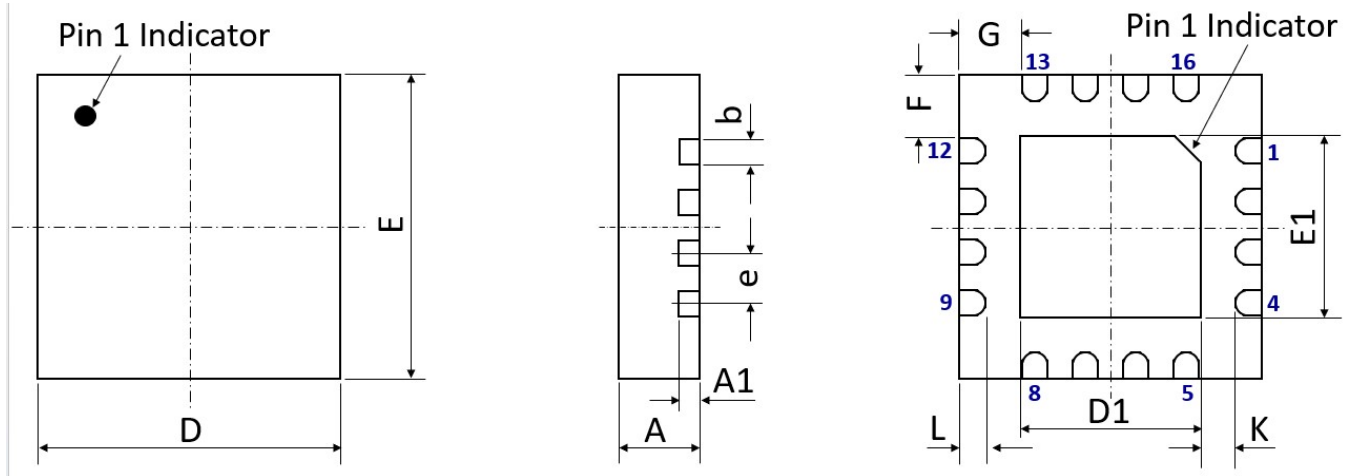


Figure 28. Shunt configuration. No DC reference required.

Note: Shunt configurations do not require DC path to ground since the ANT port is DC grounded, as shown in Fig. 18.

### 13.0 Device Package Information



**Figure 19 Device Package Drawing**  
(All dimensions are in mm)

**Table 7 Device Package Dimensions**

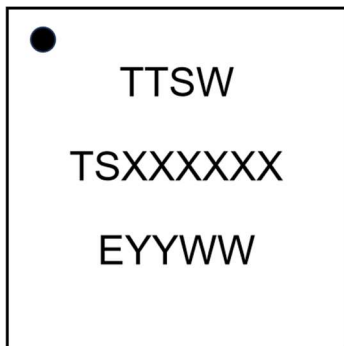
| Dimension (mm) | Value (mm) | Tolerance (mm) | Dimension (mm) | Value (mm) | Tolerance (mm) |
|----------------|------------|----------------|----------------|------------|----------------|
| A              | 0.80       | ±0.05          | E              | 3.00 BSC   | ±0.05          |
| A1             | 0.203      | ±0.02          | E1             | 1.70       | ±0.05          |
| b              | 0.25       | +0.05/-0.07    | F              | 0.625      | ±0.05          |
| D              | 3.00 BSC   | ±0.05          | G              | 0.625      | ±0.05          |
| D1             | 1.70       | ±0.05          | L              | 0.25       | ±0.05          |
| e              | 0.50 BSC   | ±0.05          | K              | 0.40       | ±0.05          |

**Note:** Lead finish: Pure Sn without underlayer; Thickness: 7.5µm ~ 20µm (Typical 10µm ~ 12µm)

**Attention:**

Please refer to application notes [TN-001](#) and [TN-002](#) at <http://www.tagoretech.com> for PCB and soldering related guidelines.

**Top-marking specification:**



● = Pin 1 indicator

TTSW = Tagore Technology SWitch

TSXXXXXX = Part number (8 digits max)

E = A fixed letter before the date code

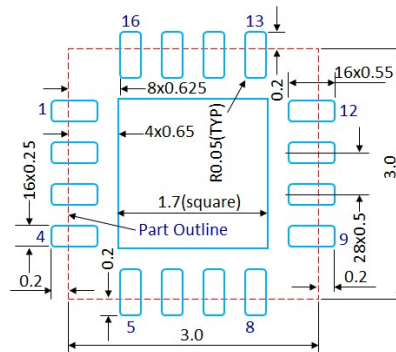
YY = Last two digits of assembly year

WW = Assembly work week

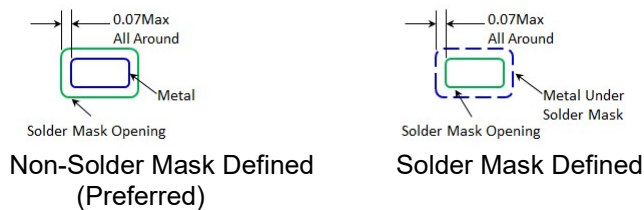
## 14.0 PCB Land Design

### Guidelines:

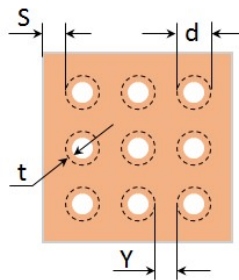
- [1] 4 layer PCB is recommended.
- [2] Via diameter is recommended to be 0.2mm to prevent solder wicking inside the vias.
- [3] Thermal vias shall only be placed on the center pad.
- [4] The maximum via number for the center pad is  $3(X) \times 3(Y) = 9$ .



**Figure 20 PCB Land Pattern**  
(Dimensions are in mm)



**Figure 21 Solder Mask Pattern**  
(Dimensions are in mm)



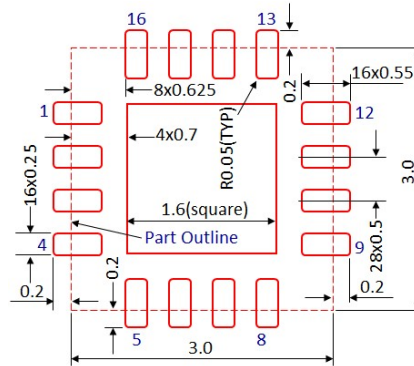
### Figure 22 Thermal Via Pattern

(Recommended Values:  $S \geq 0.15\text{mm}$ ;  $Y \geq 0.20\text{mm}$ ;  $d = 0.2\text{mm}$ ; Plating Thickness  $t = 25\mu\text{m}$  or  $50\mu\text{m}$ )

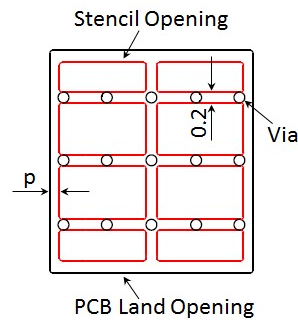
## 15.0 PCB Stencil Design

### Guidelines:

- [1] Laser-cut, stainless steel stencil is recommended with electro-polished trapezoidal walls to improve the paste release.
- [2] Stencil thickness is recommended to be 125 $\mu$ m.

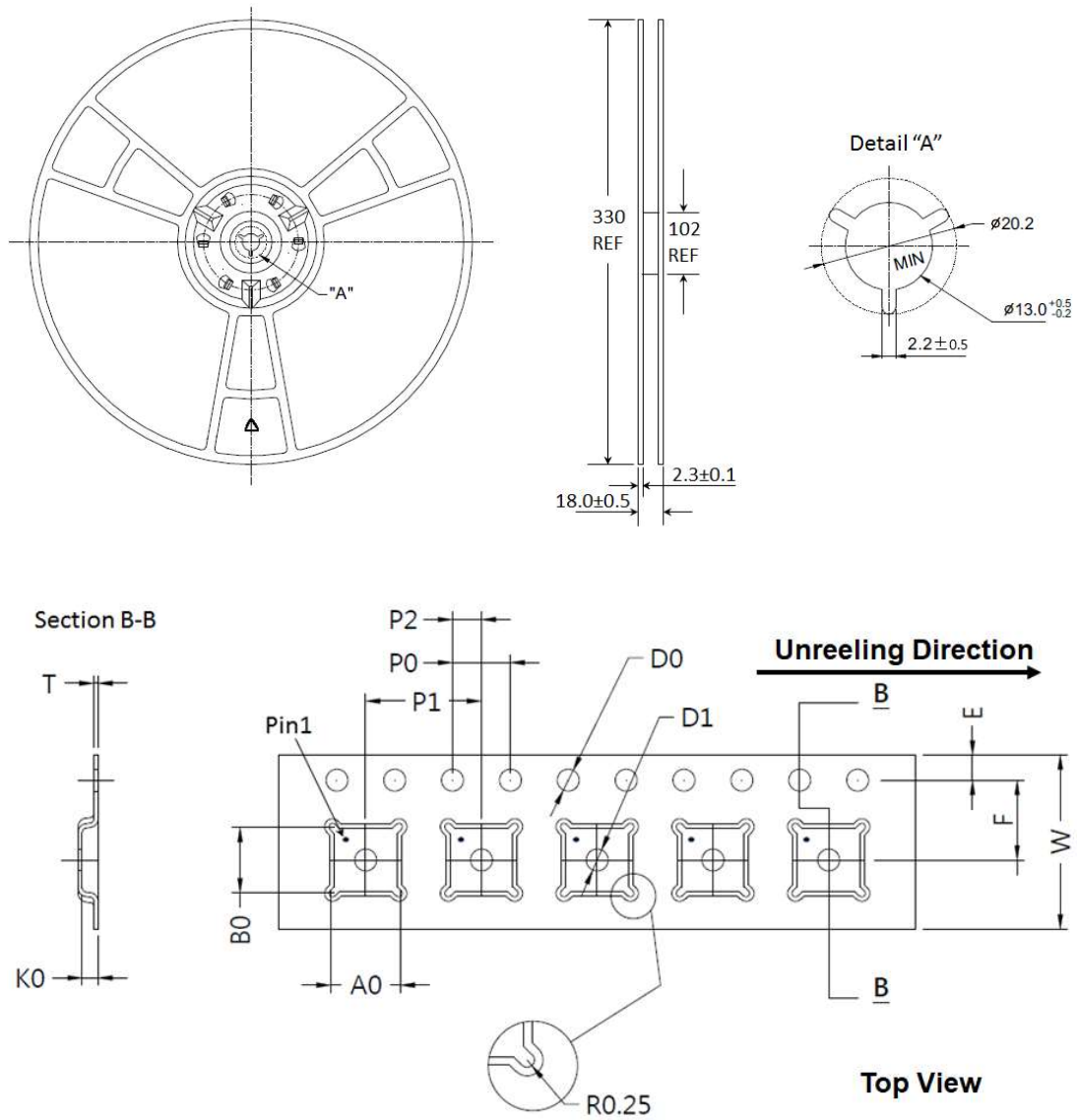


**Figure 23 Stencil Openings**  
(Dimensions are in mm)



**Figure 24 Stencil Openings Shall not Cover Via Areas If Possible**  
(Dimensions are in mm)

## 16.0 Tape and Reel Information



**Figure 25 Tape and Reel Drawing**

**Table 8 Tape and Reel Dimensions**

| Dimension (mm) | Value (mm) | Tolerance (mm) | Dimension (mm) | Value (mm) | Tolerance (mm) |
|----------------|------------|----------------|----------------|------------|----------------|
| A0             | 3.35       | ±0.10          | K0             | 1.10       | ±0.10          |
| B0             | 3.35       | ±0.10          | P0             | 4.00       | ±0.10          |
| D0             | 1.50       | +0.10/-0.00    | P1             | 8.00       | ±0.10          |
| D1             | 1.50       | +0.10/-0.00    | P2             | 2.00       | ±0.05          |
| E              | 1.75       | ±0.10          | T              | 0.30       | ±0.05          |
| F              | 5.50       | ±0.05          | W              | 12.00      | ±0.30          |

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